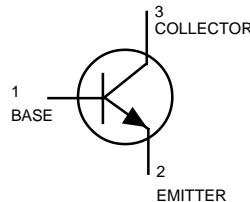


# General Purpose Transistors

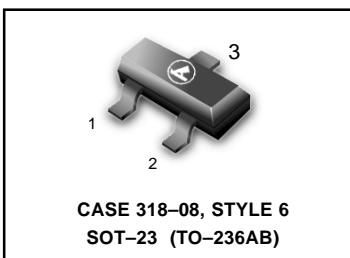
## NPN Silicon



### MAXIMUM RATINGS

Rating	Symbol	2222	2222A	Unit
Collector-Emitter Voltage	$V_{CEO}$	30	40	Vdc
Collector-Base Voltage	$V_{CBO}$	60	75	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	6.0	Vdc
Collector Current — Continuous	$I_C$	600	600	mAdc

**MMBT2222LT1  
MMBT2222ALT1**



### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$	$P_D$	225	mW
Derate above $25^\circ\text{C}$		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	$P_D$	300	mW
Derate above $25^\circ\text{C}$		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### DEVICE MARKING

MMBT2222LT1 = M1B; MMBT2222ALT1 = 1P;

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ( $I_C = 10 \mu\text{Adc}, I_B = 0$ )	MMBT2222 MMBT2222A	$V_{(BR)CEO}$	30 40	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10 \mu\text{Adc}, I_E = 0$ )	MMBT2222 MMBT2222A	$V_{(BR)CBO}$	60 75	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu\text{Adc}, I_C = 0$ )	MMBT2222 MMBT2222A	$V_{(BR)EBO}$	5.0 6.0	—	Vdc
Collector Cutoff Current ( $V_{CE} = 60 \text{ Vdc}, I_{EB(off)} = 3.0 \text{ Vdc}$ )	MMBT2222A	$I_{CEX}$	—	10	nAdc
Collector Cutoff Current ( $V_{CB} = 50 \text{ Vdc}, I_E = 0$ )	MMBT2222	$I_{CBO}$	—	0.01	$\mu\text{Adc}$
( $V_{CB} = 60 \text{ Vdc}, I_E = 0$ )	MMBT2222A		—	0.01	
( $V_{CB} = 50 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}$ )	MMBT2222		—	10	
( $V_{CB} = 60 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}$ )	MMBT2222A		—	10	
Emitter Cutoff Current ( $V_{EB} = 3.0 \text{ Vdc}, I_C = 0$ )	MMBT2222A	$I_{EBO}$	—	100	nAdc
Base Cutoff Current ( $V_{CE} = 60 \text{ Vdc}, V_{EB(off)} = 3.0 \text{ Vdc}$ )	MMBT2222A	$I_{BL}$	—	20	nAdc

1. FR-5 =  $1.0 \times 0.75 \times 0.062 \text{ in.}$

2. Alumina =  $0.4 \times 0.3 \times 0.024 \text{ in. } 99.5\% \text{ alumina.}$

**MMBT2222LT1 MMBT2222ALT1**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS</b>				
DC Current Gain ( $I_C = 0.1 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ )	$h_{FE}$	35	—	—
( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ )		50	—	—
( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ )		75	—	—
( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $T_A = -55^\circ\text{C}$ )	MMBT2222A only	35	—	—
( $I_C = 150 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ ) (3)		100	300	—
( $I_C = 150 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ ) (3)		50	—	—
( $I_C = 500 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ ) (3)	MMBT2222	30	—	—
	MMBT2222A	40	—	—
Collector-Emitter Saturation Voltage(3)	$V_{CE(\text{sat})}$			Vdc
( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ )	MMBT2222	—	0.4	
	MMBT2222A	—	0.3	
( $I_C = 500 \text{ mA}_\text{dc}$ , $I_B = 50 \text{ mA}_\text{dc}$ )	MMBT2222	—	1.6	
	MMBT2222A	—	1.0	
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$			Vdc
( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ )	MMBT2222	—	1.3	
	MMBT2222A	0.6	1.2	
( $I_C = 500 \text{ mA}_\text{dc}$ , $I_B = 50 \text{ mA}_\text{dc}$ )	MMBT2222	—	2.6	
	MMBT2222A	—	2.0	

**SMALL-SIGNAL CHARACTERISTICS**

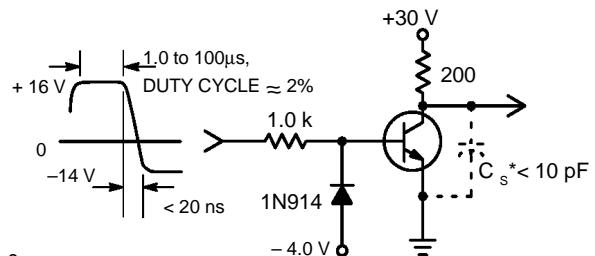
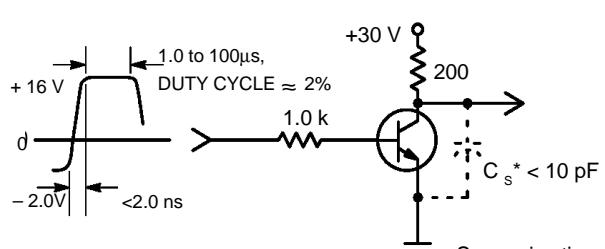
Current-Gain — Bandwidth Product(4) ( $I_C = 20 \text{ mA}_\text{dc}$ , $V_{CE} = 20 \text{ V}_\text{dc}$ , $f = 100 \text{ MHz}$ )	MMBT2222	$f_T$	250	—	MHz
	MMBT2222A		300	—	
Output Capacitance( $V_{CB} = 10 \text{ V}_\text{dc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )		$C_{obo}$	—	8.0	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ V}_\text{dc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	MMBT2222	$C_{ibo}$	—	30	pF
	MMBT2222A		—	25	
Input Impedance( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 1.0 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ ) ( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 10 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	MMBT2222A	$h_{ie}$	2.0	8.0	kΩ
	MMBT2222A		0.25	1.25	
Voltage Feedback Ratio( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 1.0 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ ) ( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 10 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	MMBT2222A	$h_{re}$	—	8.0	$\times 10^{-4}$
	MMBT2222A		—	4.0	
Small-Signal Current Gain( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 1.0 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ ) ( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 10 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	MMBT2222A	$h_{fe}$	50	300	—
	MMBT2222A		75	375	
Output Admittance( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 1.0 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ ) ( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 10 \text{ mA}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	MMBT2222A	$h_{oe}$	5.0	35	μhos
	MMBT2222A		25	200	
Current Base Time Constant ( $V_{CB} = 20 \text{ V}_\text{dc}$ , $I_E = 20 \text{ mA}_\text{dc}$ , $f = 31.8 \text{ MHz}$ )	MMBT2222A	$rb, C_C$	—	150	ps
Noise Figure( $V_{CE} = 10 \text{ V}_\text{dc}$ , $I_C = 100 \mu\text{A}_\text{dc}$ , $R_S = 1.0 \text{ k}\Omega$ , $f = 1.0 \text{ kHz}$ )	MMBT2222A	NF	—	4.0	dB

**SWITCHING CHARACTERISTICS**

Delay Time	( $V_{CC} = 30 \text{ V}_\text{dc}$ , $V_{EB(\text{off})} = -0.5 \text{ V}_\text{dc}$ )	$t_d$	—	10	ns
Rise Time	$I_C = 150 \text{ mA}_\text{dc}$ , $I_{B1} = 15 \text{ mA}_\text{dc}$	$t_r$	—	25	
Storage Time	( $V_{CC} = 30 \text{ V}_\text{dc}$ , $I_C = 150 \text{ mA}_\text{dc}$ )	$t_s$	—	225	ns
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}_\text{dc}$	$t_f$	—	60	

 3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

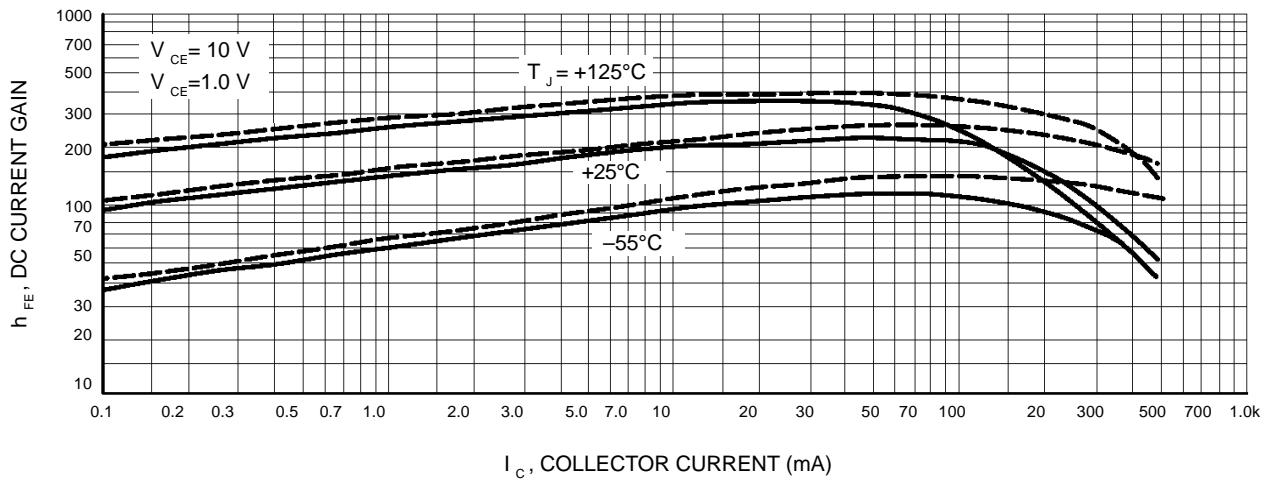
 4.  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

**MMBT2222LT1 MMBT2222ALT1**
**SWITCHING TIME EQUIVALENT TEST CIRCUITS**


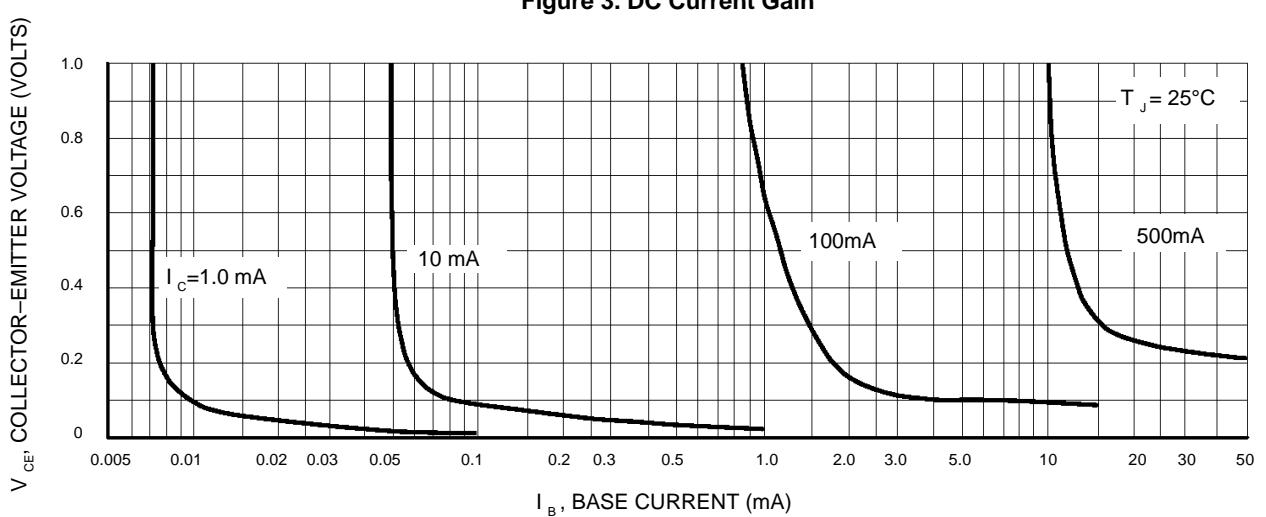
\*Total shunt capacitance of test jig, connectors, and oscilloscope.

**Figure 1. Turn-On Time**

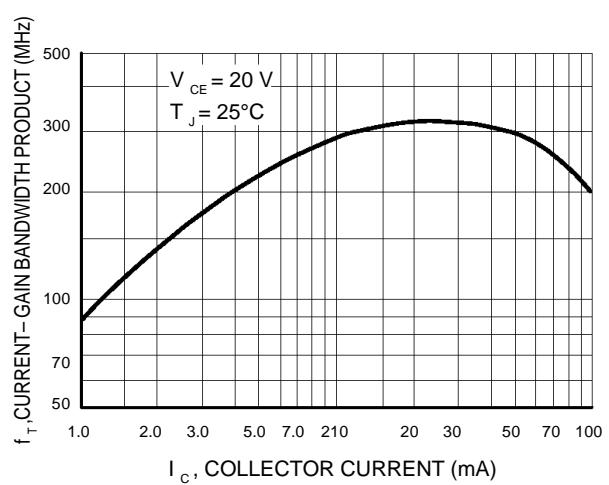
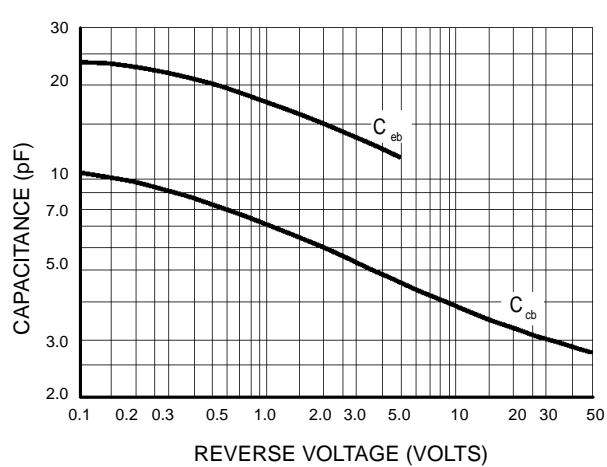
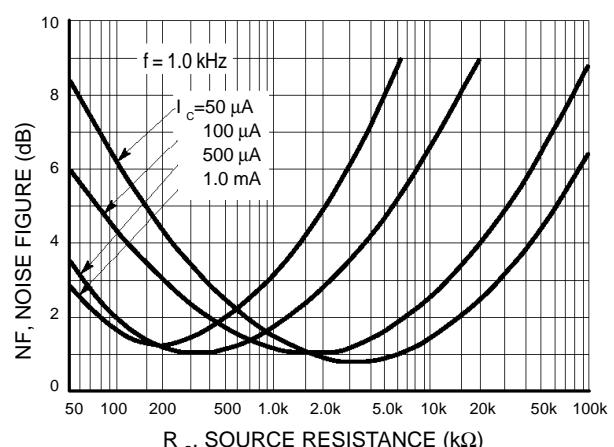
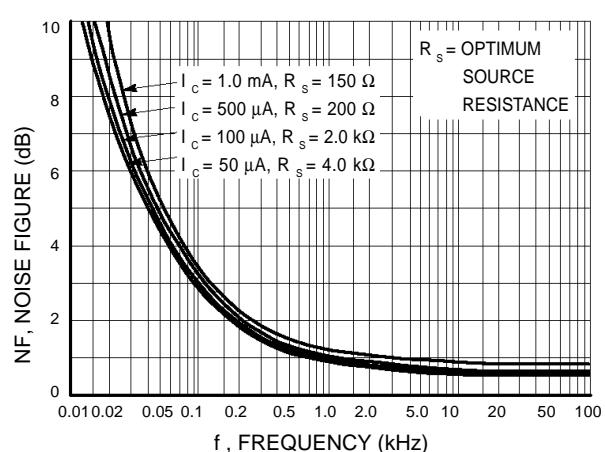
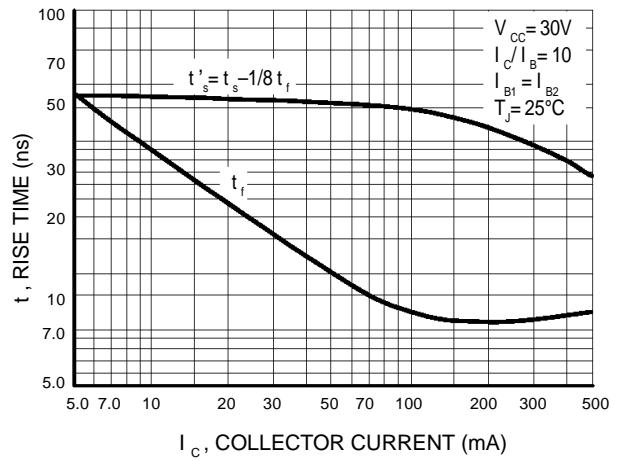
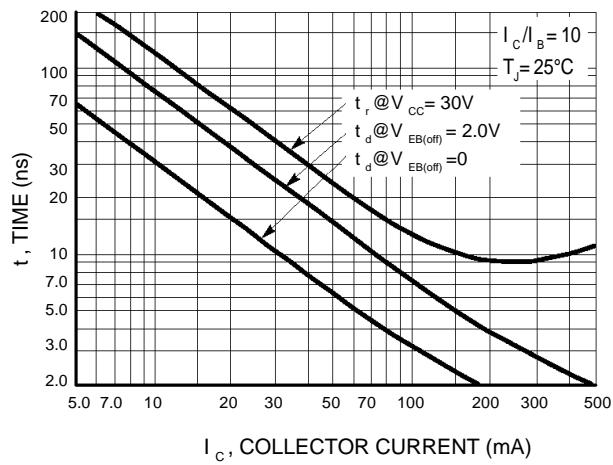
**Figure 2. Turn-Off Time**

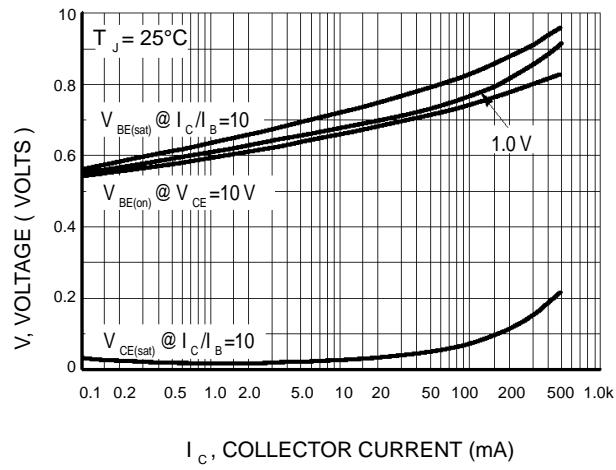


**Figure 3. DC Current Gain**



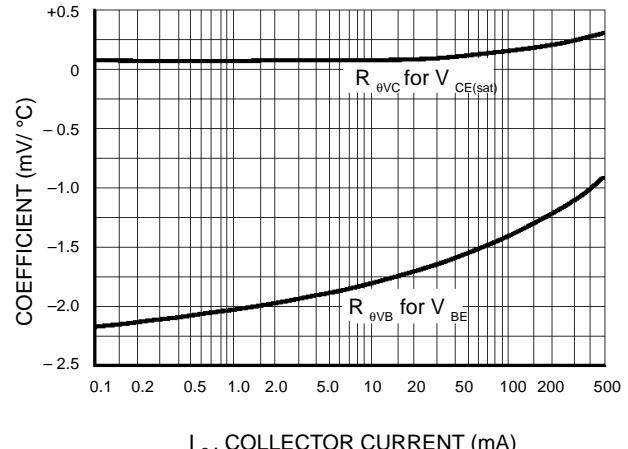
**Figure 4. Collector Saturation Region**

**MMBT2222LT1 MMBT2222ALT1**


**MMBT2222LT1 MMBT2222ALT1**


$I_C$ , COLLECTOR CURRENT (mA)

**Figure 11. "On" Voltages**



$I_C$ , COLLECTOR CURRENT (mA)

**Figure 12. Temperature Coefficients**